

P-Channel -20V (D-S) Power MOSFET

Features

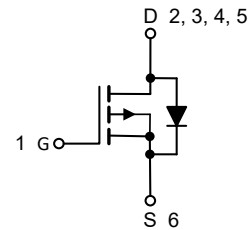
- 100% Avalanche Tested
- Halogen Free, Pb-Free
- RoHS Compliant



SOT-23-6

Applications

- Relay driver
- Switching circuits
- High-side load switch
- High-speed line driver



Absolute Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain Source Voltage	V_{DS}	-20	V
Gate Source Voltage	V_{GS}	± 12	V
Drain Current, Continuous $V_{GS}=-10\text{V}$	I_D	-5	A
$T_C=25^\circ\text{C}$			
Drain Current, Pulsed (Note 1)	I_{DM}	-20	A
Power Dissipation	P_D	1.4	W
$T_C=25^\circ\text{C}$			
Operating Junction/ Storage Temperature Range	T_J / T_{STG}	-55 to +150	$^\circ\text{C}$

Note 1: Single pulse; $t_p \leq 1\mu\text{s}$.

Thermal Characteristics

Parameter	Symbol	Max	Unit
Thermal Resistance Junction to Ambient (Note 2)	R_{thJA}	90	$^\circ\text{C/W}$

Note 2: Device mounted on 1 square inch FR4 PCB board, with 2oz single-sided copper, in a 25°C still air environment.

Electrical Characteristics (T_A =25°C unless otherwise noted)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Drain Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =-250μA	-20	--	--	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-20V, V _{GS} =0V	--	--	1	uA
Gate Threshold Voltage	V _{GS(TH)}	V _{DS} =V _{GS} , I _{DS} =-250uA	-0.5	--	-1	V
Gate Leakage Current	I _{GSS}	V _{GS} =±12V, V _{DS} =0V	--	--	±100	nA
Drain-Source On-state Resistance (Note 3)	R _{DS(on)}	V _{GS} =-4.5V, I _D =-5A	--	29	35	mΩ
		V _{GS} =-2.5V, I _D =-3A	--	36	48	
Total Gate Charge	Q _g	V _{GS(off)} =0V, V _{GS(on)} =-5V, V _{DD} =-10V, I _D =-4.5A	--	12	--	nC
Gate-Source Charge	Q _{gs}		--	1.3	--	
Gate-Drain Charge	Q _{gd}		--	3.5	--	
Turn-on Delay Time	t _{d(on)}	V _{GS} =-4.5V, V _{DD} =-10V, R _L =2.5Ω, R _G =3Ω	--	11	--	ns
Turn-on Rise Time	t _r		--	10	--	
Turn-off Delay Time	t _{d(off)}		--	17	--	
Turn-off Fall Time	t _f		--	22	--	
Input Capacitance	C _{iss}	V _{GS} =0V, V _{DS} =-20V, f=1MHz	--	874	--	pF
Output Capacitance	C _{oss}		--	99	--	
Reverse Transfer Capacitance	C _{rss}		--	86	--	

Reverse Diode Characteristics (T_A =25°C unless otherwise noted)

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Forward Current, Continuous	I _{SD}	T _C =25°C	--	--	-5	A
Diode Forward Voltage (Note 3)	V _{SD}	I _F =-1.3A, V _{GS} =0V	--	--	-1.3	V

Note 3: Pulse test; pulse width ≤ 380μs, duty cycle ≤ 1%.

Typical Characteristics Curves ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Fig.1 - Output Characteristics

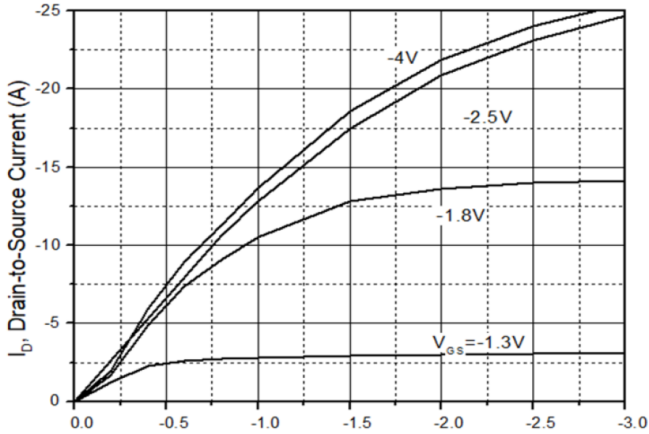


Fig.3 - Capacitance

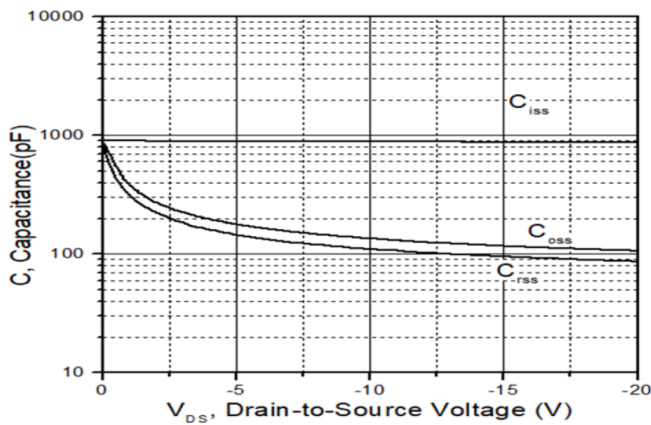


Fig.5 - Safe Operating Area

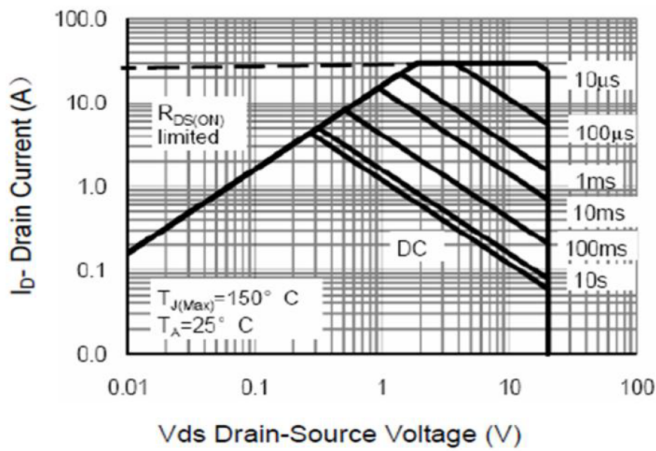


Fig.2 - Transfer Characteristics

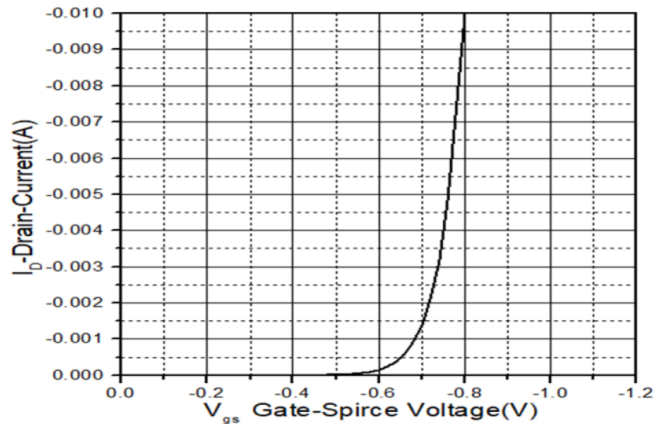


Fig.4 - Gate charge

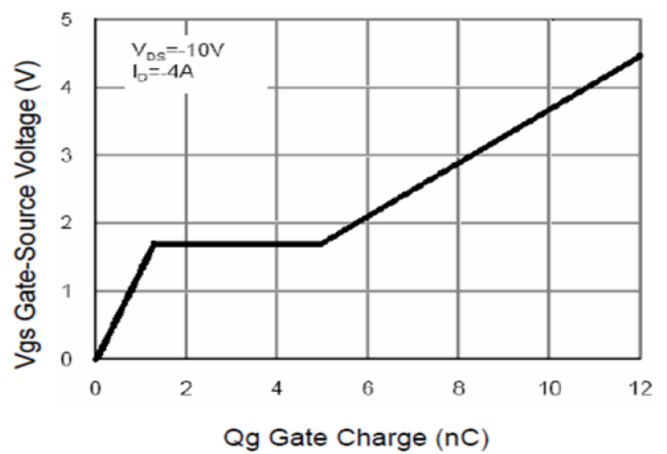
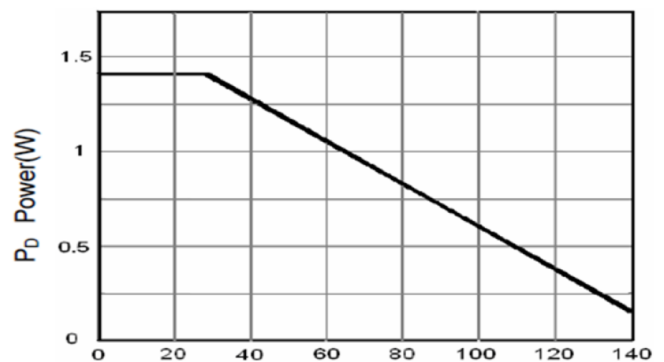
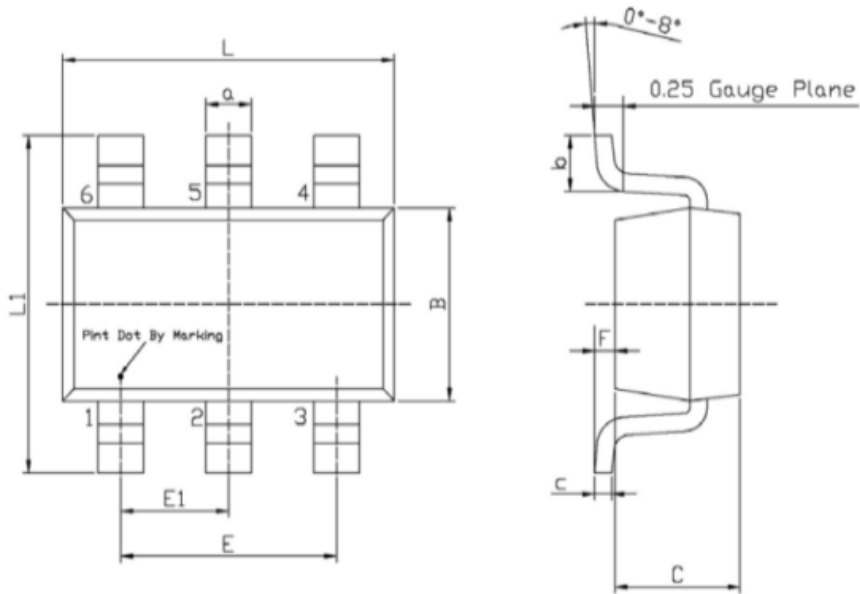


Fig.6 - Power Derating



Package Outline Dimensions (Unit: millimeters)

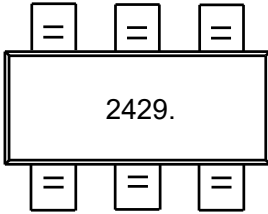
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Unit: mm

Symbol	Dimensions In Millimeters		Symbol	Dimensions In Millimeters	
	Min	Max		Min	Max
L	2.82	3.02	E1	0.85	1.05
B	1.50	1.70	a	0.35	0.50
C	0.90	1.30	c	0.10	0.20
L1	2.60	3.00	b	0.35	0.55
E	1.80	2.00	F	0	0.15

Marking Outline



Part Name: GMP2429UP

1. P/N Mark: 2429.

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